

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	'6051503' pn.	USPAT	OR	ON	2004/12/27 07:52
L2	35370	plasma and (etch or etching) and semiconductor	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/27 07:56
L3	119	2 and ((ramp or ramping) and (etch\$1stop\$3 or (etch adj stop\$3)))	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/27 07:57
L4	0	jacobs-Keren.in.	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/27 07:57
L5	0	Jacobs-Keren.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/27 07:58
L6	5	Eppler-Aaron.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/27 07:58
L7	272	plasma and selectivity and (ramp or ramping) and pressure	US-PGPUB; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/27 07:59
S30 1	4966	damascene	USPAT	OR	ON	2004/11/12 14:09
S30 2	530	S301 and "CF.sub.4" and (oxygen or "O.sub.2")	USPAT	OR	ON	2004/11/12 14:10
S30 3	277	S301 and ("CF.sub.4" with (oxygen or "O.sub.2"))	USPAT	OR	ON	2004/11/12 14:11
S30 4	103	S303 and ((nitrogen or "N.sub.2") with (hydrogen or "H.sub.2"))	USPAT	OR	ON	2004/11/12 14:16
S30 5	86	S304 and @ay<="2001"	USPAT	OR	ON	2004/11/12 14:16
S30 6	326	plasma and selectivity and (ramp or ramping) and pressure	USPAT	OR	ON	2004/12/27 07:59
S30 7	297	S306 and @py<="2003"	USPAT	OR	ON	2004/11/22 15:15

S308	175	S307 and (controller or processor or computer)	USPAT	OR	ON	2004/11/22 15:17
S309	109	S308 and (etch or etching)	USPAT	OR	ON	2004/11/22 15:17
S310	621	(third near4 plasma) and (selectivity or selective)	USPAT	OR	ON	2004/11/22 16:00
S311	420	S310 and @ay<="2003" and semiconductor	USPAT	OR	ON	2004/11/22 16:00
S312	388	S311 and (etch or etching)	USPAT	OR	ON	2004/11/22 16:01
S313	86	S312 and (etch\$1stop or (etch\$3 adj stop) or (etch\$3 adj stopping))	USPAT	OR	ON	2004/11/22 16:01
S314	84	S313 and @py<="2003"	USPAT	OR	ON	2004/11/22 17:29
S315	1	"6638781".pn.	USPAT	OR	ON	2004/11/22 17:30
S316	1	"6638871".pn.	USPAT	OR	ON	2004/11/22 17:37
S317	3	"4729815".pn. "5807789".pn. "5843226".pn.	USPAT	OR	ON	2004/11/22 17:37
S318	1	"6762132".pn.	USPAT	OR	ON	2004/11/29 13:32
S319	1	"6051503".pn.	USPAT	OR	ON	2004/11/29 14:57
S320	42678	plasma and (etch or etching) and semiconductor	USPAT	OR	ON	2004/12/27 07:56
S321	3	S320 and ((ramp or ramping) same (etch\$1stop\$3 or (etch adj Stop\$3)))	USPAT	OR	ON	2004/11/29 14:58
S322	170	S320 and ((ramp or ramping) and (etch\$1stop\$3 or (etch adj stop\$3)))	USPAT	OR	ON	2004/12/27 07:57
S323	119	S322 and @py<="2002"	USPAT	OR	ON	2004/11/29 14:59
S324	5202	S320 and controller	USPAT	OR	ON	2004/11/29 15:37
S325	1227	S324 and outlet	USPAT	OR	ON	2004/11/29 15:37
S326	1130	S325 and chamber	USPAT	OR	ON	2004/11/29 15:38
S327	494	S326 and (computer or CPU)	USPAT	OR	ON	2004/11/29 15:38
S328	479	S327 and pressure	USPAT	OR	ON	2004/11/29 15:38

S32 9	479	S328 and chamber	USPAT	OR	ON	2004/11/29 15:39
S33 0	313	S329 and electrode	USPAT	OR	ON	2004/11/29 15:39
S33 1	222	S330 and @py<="2002"	USPAT	OR	ON	2004/11/29 16:07
S33 2	1	"6025255":pn.	USPAT	OR	ON	2004/11/29 16:39
S33 3	4	(ramp or ramping) same (etch\$1stop\$4 or (etch adj stop\$4))	USPAT	OR	ON	2004/11/29 16:44
S33 4	712	rate with (etch\$1stop\$4 or (etch adj stop\$4))	USPAT	OR	ON	2004/11/29 16:44
S33 5	0	S334 and semiconductor and plasma	USPAT	OR	ON	2004/11/29 16:45
S33 6	488	S334 and semiconductor and plasma	USPAT	OR	ON	2004/11/29 16:45
S33 7	481	S336 and @ay<="2002"	USPAT	OR	ON	2004/11/29 16:45
S33 8	27	S337 and (ramp or ramping)	USPAT	OR	ON	2004/11/29 16:45